



40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BVDSS	Rds(on) Max	I _D Max T _C = +25°C
40V	8.9mΩ @ V _{GS} = 10V	52.4A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor Control
- Power Management Functions
- DC-DC Converters

Features and Benefits

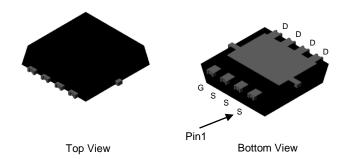
- Excellent Qgd x Rds(ON) Product (FOM)
- Low RDS(ON) Ensures On-State Losses Minimized
- 100% Unclamped Inductive Switching, Test in Production Ensures More Reliable and Robust End Application
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH48M3SFVWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

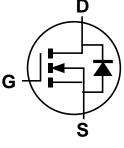
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208(§3)
- Weight: 0.072 grams (Approximate)

PowerDI3333-8 (SWP) (Type UX)





Equivalent Circuit

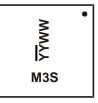
Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH48M3SFVWQ-7	PowerDI3333-8 (SWP) (Type UX)	2,000/Tape & Reel
DMTH48M3SFVWQ-13	PowerDI3333-8 (SWP) (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



 $\begin{array}{l} \underline{\text{M3S}} = \text{Product Type Marking Code} \\ \underline{\overline{\text{YY}}} \text{WW} = \text{Date Code Marking} \\ \underline{\overline{\text{YY}}} = \text{Last Two Digits of Year (ex: 20 = 2020)} \\ \text{WW} = \text{Week Code (01 to 53)} \end{array}$

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A =+ 25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	40	V		
Gate-Source Voltage		Vgss	±20	V	
Continuous Dusin Comment (Note C) 1/ 401/	Tc = +25°C	1-	52.4	Δ.	
Continuous Drain Current (Note 6), V _{GS} = 10V	Tc = +100°C	ID	37.1	A	
0 1	T _A = +25°C		14.6	Δ.	
Continuous Drain Current (Note 5), V _{GS} = 10V	T _A = +100°C	lD	10.3	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	209	А		
Maximum Continuous Body Diode Forward Current (Note 6)	Is	40.6	А		
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 19	Ism	209	Α		
Avalanche Current, L = 0.1mH	las	24.7	А		
Avalanche Energy, L = 0.1mH	Eas	30.5	mJ		

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5) $T_A = +25^{\circ}C$		PD	2.82	W
Thermal Resistance, Junction to Ambient (Note 5)	RθJA	52.6	°C/W	
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	36.6	W
Thermal Resistance, Junction to Case (Note 6)		Rелс	4.09	°C/W
Operating and Storage Temperature Range	Т _J , Тsтg	-55 to +175	°C	

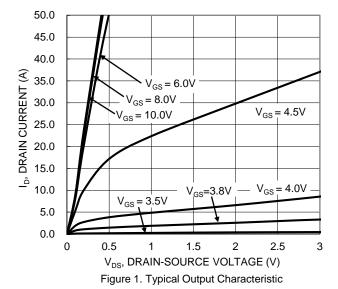
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

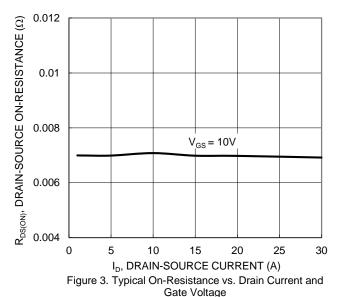
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	40	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	$V_{DS} = 32V$, $V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	2	2.7	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	6.9	8.9	mΩ	$V_{GS} = 10V, I_{D} = 20A$	
Diode Forward Voltage	V_{SD}	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	897	_		V _{DS} = 20V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	530	_	pF		
Reverse Transfer Capacitance	Crss	_	12.4	_			
Gate Resistance	R_g	_	2.07	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	12.1	_		V _{DS} = 20V, I _D = 20A, V _{GS} = 10V	
Gate-Source Charge	Q_{gs}	_	2.0	_	nC		
Gate-Drain Charge	Q_{gd}	_	1.9	_			
Turn-On Delay Time	tD(ON)	_	5.36	_		$\begin{split} V_{DD} &= 20 \text{V}, V_{GS} = 10 \text{V}, \\ R_g &= 3 \Omega, I_D = 20 \text{A} \end{split}$	
Turn-On Rise Time	t _R	_	4.54	_	ns		
Turn-Off Delay Time	tD(OFF)	_	12.1	_	ns		
Turn-Off Fall Time	tF		5.59	_			
Body Diode Reverse Recovery Time	trr		39.1		ns	I_ 20A di/dt 100A/us	
Body Diode Reverse Recovery Charge	Qrr	_	53.3	_	nC	I _F = 20A, di/dt = 100A/μs	

Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.







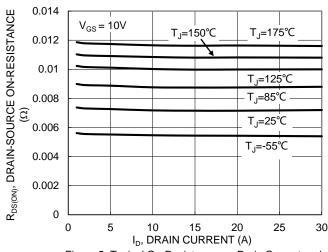
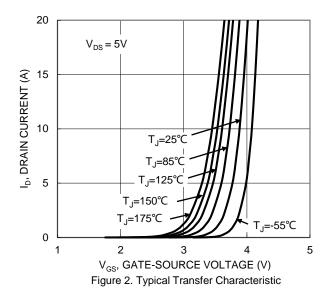
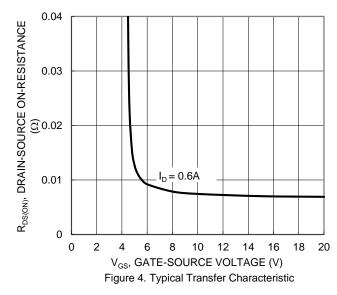


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





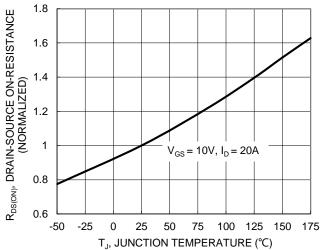


Figure 6. On-Resistance Variation with Junction Temperature



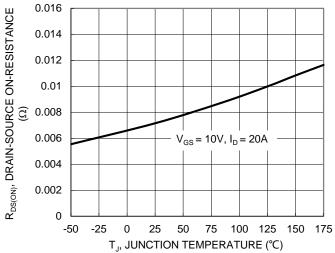
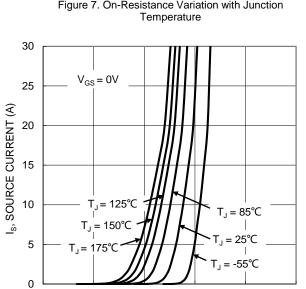


Figure 7. On-Resistance Variation with Junction



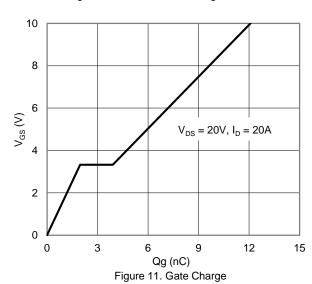
V_{SD}, SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current

0.6

0.9

1.2

1.5



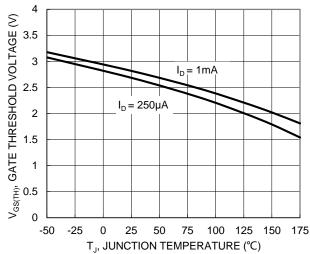
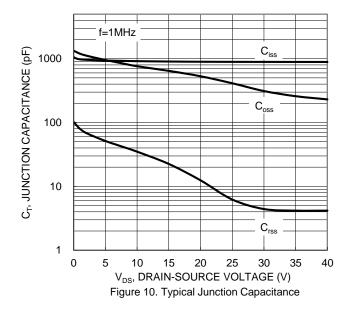
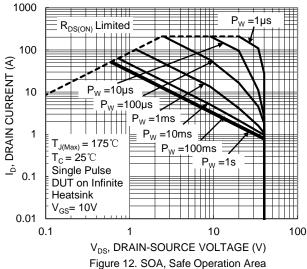


Figure 8. Gate Threshold Variation vs. Junction Temperature





0

0.3



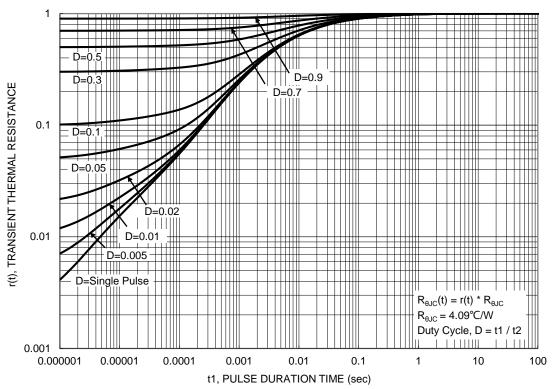


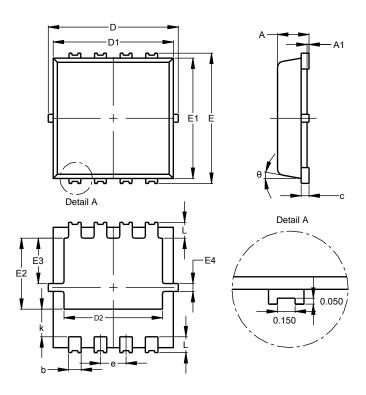
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

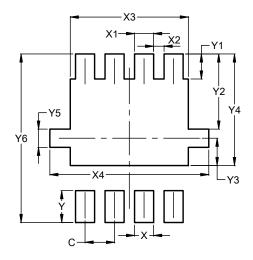


PowerDI3333-8 (SWP)						
	(Type UX)					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.600		
X4	3.500		
Υ	0.700		
Y1	0.550		
Y2	1.650		
Y3	0.600		
Y4	2.450		
Y5	0.400		
Y6	3.700		



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